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PUCV 3-2018





What is Photovoltaics ?



with Pabitra Nayak (Oxford U.)

G. Hodes, L. Barnea, R. Milo (WIS), A. Kahn (PU) + all those mentioned on the slides,++++++





A Solar Cell does not require a p-n junction!

E. Yablonovich, UCB © 2015

Conventional p-n Junction Solar Cell



- Absorbs light
- Absorbed light creates carriers
- Carriers collection, by diffusion/ drift

Conventional p-n Junction Solar Cell + I-V characteristics



after textbooks & R. Collins, CSM

A schematic of a p-n junction Solar Cell



The Photovoltaic (PV) effect: Generalized picture¹



space

Inspired by RT Ross, JAP (1967);
cf. e.g., MA Green, Physica E (2002)
same principle for photosynthesis

Metastable high and low energy states

Absorber transfers charges into high and low energy state

Driving force brings charges to contacts

Selective contacts

high voltage / current / efficiency, requires to collect all carriers!

Current Types of PV Cells



Types of junction for solar cells **Homojunctions** (c-Si, GaAs,



Types of junction for solar cells: **Heterojunctions** Thin film Cd(Se,Te), Cu(In,Ga)Se₂ = CIGS, Halide Perovskite



Schottky barrier



p-i-n junction



One type of Organic Solar Cell Architecture



Solar Cell (r)evolutions

1st generation

Si



2nd generation CdTe, CIGS



Single- crystalline µm

In 11/2017 Global *Cumulative* Installed PV Power ~ 0.32 TW_p PRC goal >2012 $\geq 0.01 \text{ TW}_p/\text{yr}$ 3^d generation TiO₂ Small molecule/ halide perovskite, QDs



nano / meso crystalline ~ 20 nm





amorphous (a-Si:H; polymers)

| Lowest Loss Single Junction PV lab cells | | | | | | | | |
|--|--|--------------------|--|--|--|--|--|--|
| (1-4 cm ² ; most tandems are much smaller; 2010 values in blue) | | | | | | | | |
| ~ | [71] 29 % GaAs | ~26 % | | | | | | |
| ~ | [74] 26.7 % single crystal Si (79 cm ²) | ~25 % | | | | | | |
| ~ | [79] 21-22 % PX thin films (CIGS, CdTe, Si) | ~17 % | | | | | | |
| ~ | [79] 21 % halide perovskite | ~4 % | | | | | | |
| ~ | [88] 12 % dye-sensitized solar cell (DSSC) | ~ 10 % | | | | | | |
| ~ | [89] 11 % organic (molecules; polymers) | ~ 5 % | | | | | | |
| - | | | | | | | | |
| ~ | [61%] 39 % tandem quintuple junction | | | | | | | |
| (~ [54%] 46 % bigger Mac" <i>tandem</i> triple junction ~ 36 % (~ [54%] 46 % bigger Mac" <i>tandem</i> , @ 500 x concentration) ~ 41.5% | | | | | | | | |
| | Definition of efficiency: | | | | | | | |
| | $= \frac{Electrical}{Power_{OUT}} \times 100\%$ | | | | | | | |
| | Solar Radiative P | ower _{IN} | | | | | | |

Data from Solar Cell Eff #50, Progr in PV 2017 and other sources

Possibilities for Technological Progress

2010 values in blue

| Efficiency(%) Manufacture | | Technology (area, if < 600 cm ²) | BEST | | | | | |
|---|----------------|---|--------------------------|--|--|--|--|--|
| | | | commercial | | | | | |
| | | | module/cell ¹ | | | | | |
| 24.1 | SunPower | Single-crystal Si non-standard jnctn | 91 <i>% 78</i> | | | | | |
| 18.2 | Panasonic | Single-crystal Si HIT jnctn | 71% ← 74 | | | | | |
| 19.2 | Trina Solar | Multi crystal Si standard junction | 90% 71 | | | | | |
| 14.3 | Evergreen | mc-Si ribbon standard junction | % | | | | | |
| ~18.6 | First Solar | CdTe | 89 % 7 65 | | | | | |
| ~14.3 | Solar Frontier | CIGS (Cd-free) | 79 % 7 58 | | | | | |
| 12.3 | Tel Solar | a-Si / nc-Si* | 69 % <u>66</u> | | | | | |
| 6.7 / 5.7 | Uni-Solar | a-Si, triple junction * | 54 % | | | | | |
| | | * stabilized values | | | | | | |
| 24.8 ^{2,3} | Alta | GaAs thin film (pilot, 860) | ~84% | | | | | |
| 8.8 ^{2,3} | Sharp | dye (pilot, 398) | ~75% 46 | | | | | |
| 9.1 ^{2,3} | Toshiba | Organic polymer/molecule (pilot, 25) | ~82% 49 | | | | | |
| 12.5 ^{3,4} | Chose-Rome | Halide Perovskite (pilotissimo, 100) | ~60% | | | | | |
| -1-1 cm ² cells; -2- Pilot modules; few yrs stability; -3- not yet commercially available; | | | | | | | | |
| 4- ; no stability data as yet | | | | | | | | |

Why do we need another Solar Cell, apart from Si ?

Well, what does PV need most?

SOFT COSTS ARE THE MAJOR DRIVER OF COST DIFFERENCES BETWEEN THE U.S. AND GERMANY

Solar PV Costs in the USA and Germany (2013)



(Hard & "Soft" Balance of Systems Costs) scale ∝ area To > [(€-\$-¥)/area] need to PV efficiency

To minimize all non-PV costs, we need more W (& Wh) / area / €-\$-¥



*Permitting, Inspection, and Interconnection costs

Sys

** Includes installer and integrator margin, legal fees, professional fees, financing transactional costs, O+M costs, production guarantees, reserves, and warranty costs.

Just Si will go only so far, because a PV cell is not very efficient...

Reminder: Solar Irradiance and power density



Figure from : http://en.wikipedia.org/wiki/Air_mass_(solar_energy)

PK NAYAK, OXFORD U

because in Solar Cells Most Energy is "Lost" as Heat Quantum (threshold) Conversion Process





O. Niitsoo

Inside a p/n junction Solar Cell



Power Losses in Solar Cells

thickness of the solar cell: approx 0,3 mm thickness of the n-semiconductor layer: approx 0,002 mm anti-reflection film



David Cahen

Losses in PV cell



Shockley-Queisser* (SQ) Limit

* detailed balance, photons-in = electrons-out + photons out; on earth, @ RT, for single absorber / junction;



Shockley-Queisser **model** assumes step function optical absorption (and EQE)



Photovoltaic Solar cell Efficiencies (≤ 2012)





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K.Leo 2012

From 2013 till now

From 4 % to > 23 % solar cell efficiency in 7 years!



Halide Perovskite Solar Cell Architecture (~ OPV)



Evolution of EQE in halide perovskite cells



Improvements of low energy quantum efficiencies

Current efficiencies

 $J_{SC}/q \int \phi(v) dv = (J_{SC}/J_{SC}^{\max})$

| Cell type (<i>absorber</i>) | RT bandgap abs. edge [eV] | J _{sc} ^{max} [mA/cm ²] | J _{sc} * [mA/cm ²] | J _{sc} /J _{sc} ^{max} [%] | 2010 values in blue |
|-------------------------------|------------------------------|---|--|--|---------------------------|
| sc-Si | 1.12 | 43.3 | 42.6 | 98 <i>98</i> | |
| GaAs | 1.42 | 31.7 | 29.7 | 94 <i>89</i> | |
| InP | 1.28 | 36.0 | 31.1 | 86 <mark>81</mark> | |



Maximum possible vs. experimental photocurrents



Nayak et al. Adv. Mater., 5-2011,3-2014; updated 01-2018

External quantum efficiency of several types of cells



In organic based solar cells EQE does not have sharp edge. This limits current efficiency.

Solar Cell Eff #35, Progr. in PV, 2010

Voltage efficiency: V_{OC}/E_{G}

qV_{oc} / E_G : voltage efficiency



Shockley-Queisser (•) and experimental (**••**) *LOSS* as function of minimal excitation energy



Nayak et al. Adv. Mater., 5-2011,3-2014; updated 11-2017 & TBP

Evolution of energy loss in metal halide perovskites



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What can we do about this?

Better utilization of sunlight: Photon management:

Multi-bandgap, multi-junction photovoltaics



Bandgap (eV)



remember...,there's more than PV

